



Product Overview

2N6491: Power Bipolar Transistor, NPN, 80 V, 15 A

For complete documentation, see the data sheet

Product Description

The 15 A, 80 V PNP Bipolar Power Transistor is designed for use in general-purpose amplifier and switching applications. 2N6487, 2N6488 (NPN); and 2N6490, 2N6491 (PNP) are complementary devices.

Features

- DC Current Gain Specified to 15 Amperes-- $h_{FE} = 20-150$ @ $I_C = 5.0$ Adc; $h_{FE} = 5.0$ (Min) @ $I_C = 15$ Adc
- Collector-Emitter Sustaining Voltage-- $V_{CEO(sus)} = 60$ Vdc (Min) - 2N6487, 2N6490; $V_{CEO(sus)} = 80$ Vdc (Min) - 2N6488, 2N6491
- High Current Gain--Bandwidth Product
 $f_T = 5.0$ MHz (Min) @ $I_C = 1.0$ Adc
- TO-220AB Compact Package
- Pb-Free Packages are Available

Applications

- Designed for use in general-purpose amplifier and switching applications.

Part Electrical Specifications

Product	Compliance	Status	Polarity	I_C Continuous (A)	$V_{(BR)CEO}$ Min (V)	h_{FE} Min	h_{FE} Max	f_T Min (MHz)	P_{TM} Max (W)	Package Type
2N6491G	Pb-free	Active	PNP	15	80	20	150	5	75	TO-220-3

For more information please contact your local sales support at www.onsemi.com

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